



# ADD-A-PAK Generation VII Power Modules Standard Diodes, 80 A




ADD-A-PAK

| PRODUCT SUMMARY |   |
|-----------------|---|
| $I_{F(AV)}$     | 80 A  |
| Type            | Modules - Diode, High Voltage   |
| Package         | ADD-A-PAK   |
| Circuit         | Two diodes doubler circuit,<br>Two diodes common cathode,<br>Two diodes common anode,<br>Single diode |

### MECHANICAL DESCRIPTION

The ADD-A-PAK generation VII, new generation of ADD-A-PAK module, combines the excellent thermal performances obtained by the usage of exposed direct bonded copper substrate, with advanced compact simple package solution and simplified internal structure with minimized number of interfaces.

### FEATURES

- High voltage
- Industrial standard package
- Low thermal resistance
- UL approved file E78996 
- Designed and qualified for industrial level
- Material categorization: For definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)



### BENEFITS

- Excellent thermal performances obtained by the usage of exposed direct bonded copper substrate
- Up to 1600 V
- High surge capability
- Easy mounting on heatsink

### ELECTRICAL DESCRIPTION

These modules are intended for general purpose high voltage applications such as high voltage regulated power supplies, lighting circuits, temperature and motor speed control circuits, UPS and battery charger.

| MAJOR RATINGS AND CHARACTERISTICS |                 |             |                    |
|-----------------------------------|-----------------|-------------|--------------------|
| SYMBOL                            | CHARACTERISTICS | VALUES      | UNITS              |
| $I_{F(AV)}$                       | 110 °C          | 80          | A                  |
| $I_{F(RMS)}$                      |                 | 126         |                    |
| $I_{FSM}$                         | 50 Hz           | 1500        |                    |
|                                   | 60 Hz           | 1570        |                    |
| $I^2t$                            | 50 Hz           | 11.25       | kA <sup>2</sup> s  |
|                                   | 60 Hz           | 10.26       |                    |
| $I^2\sqrt{t}$                     |                 | 112.5       | kA <sup>2</sup> √s |
| $V_{RRM}$                         | Range           | 400 to 1600 | V                  |
| $T_J$                             |                 | -40 to 150  | °C                 |
| $T_{Stg}$                         |                 |             |                    |



**ELECTRICAL SPECIFICATIONS**

| <b>VOLTAGE RATINGS</b> |              |  |  |  |
|------------------------|--------------|--|--|--|
| TYPE NUMBER            | VOLTAGE CODE | $V_{RRM}$ , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE<br>V | $V_{RSM}$ , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE<br>V | $I_{RRM}$ MAXIMUM AT $T_J = 150\text{ }^\circ\text{C}$<br>mA |
| VS-VSK.71              | 04           | 400  | 500  | 10   |
|                        | 06           | 600  | 700  |  |
|                        | 08           | 800  | 900  |  |
|                        | 10           | 1000   | 1100   |  |
|                        | 12           | 1200   | 1300   |  |
|                        | 14           | 1400   | 1500   |  |
|                        | 16           | 1600   | 1700   |  |

| <b>FORWARD CONDUCTION</b>                                     |               |   |                           |        |                    |
|---|---------------|---|---------------------------|--------|--------------------|
| PARAMETER   | SYMBOL        | TEST CONDITIONS   |                           | VALUES | UNITS              |
| Maximum average forward current at case temperature           | $I_{F(AV)}$   | 180° conduction, half sine wave   |                           | 80     | A                  |
|   |               |   |                           | 110    | °C                 |
| Maximum RMS forward current                                   | $I_{F(RMS)}$  | DC at 90 °C case temperature  |                           | 126    |                    |
| Maximum peak, one-cycle forward, non-repetitive surge current | $I_{FSM}$     | t = 10 ms   | No voltage reapplied      | 1500   | A                  |
|   |               | t = 8.3 ms  |                           | 1570   |                    |
|   |               | t = 10 ms   | 100 % $V_{RRM}$ reapplied | 1260   |                    |
|   |               | t = 8.3 ms  |                           | 1320   |                    |
| Maximum $I^2t$ for fusing                                     | $I^2t$        | t = 10 ms   | No voltage reapplied      | 11.25  | kA <sup>2</sup> s  |
|   |               | t = 8.3 ms  |                           | 10.26  |                    |
|   |               | t = 10 ms   | 100 % $V_{RRM}$ reapplied | 7.95   |                    |
|   |               | t = 8.3 ms  |                           | 7.23   |                    |
| Maximum $I^2\sqrt{t}$ for fusing                              | $I^2\sqrt{t}$ | t = 0.1 ms to 10 ms, no voltage reapplied   |                           | 112.5  | kA <sup>2</sup> √s |
| Low level value of threshold voltage                          | $V_{F(TO)1}$  | (16.7 % $\times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)}$ ), $T_J = T_J$ maximum                         |                           | 0.73   | V                  |
| High level value of threshold voltage                         | $V_{F(TO)2}$  | (I > $\pi \times I_{F(AV)}$ ), $T_J = T_J$ maximum  |                           | 0.83   |                    |
| Low level value of forward slope resistance                   | $r_{f1}$      | (16.7 % $\times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)}$ ), $T_J = T_J$ maximum                         |                           | 3.22   | mΩ                 |
| High level value of forward slope resistance                  | $r_{f2}$      | (I > $\pi \times I_{F(AV)}$ ), $T_J = T_J$ maximum  |                           | 2.89   |                    |
| Maximum forward voltage drop                                  | $V_{FM}$      | $I_{FM} = \pi \times I_{F(AV)}$ , $T_J = 25\text{ }^\circ\text{C}$ , $t_p = 400\text{ }\mu\text{s}$ square wave |                           | 1.6    | V                  |

| <b>BLOCKING</b>                      |           |                                   |  |              |       |
|--------------------------------------|-----------|-----------------------------------|--|--------------|-------|
| PARAMETER                            | SYMBOL    | TEST CONDITIONS                   |  | VALUES       | UNITS |
| Maximum peak reverse leakage current | $I_{RRM}$ | $T_J = 150\text{ }^\circ\text{C}$ |  | 10           | mA    |
| Maximum RMS insulation voltage       | $V_{INS}$ | 50 Hz                             |  | 3000 (1 min) | V     |
|                                      |           |                                   |  | 3600 (1 s)   |       |



| THERMAL AND MECHANICAL SPECIFICATIONS                         |                                   |  |                               |       |
|---|-----------------------------------|--|-------------------------------|-------|
| PARAMETER   | SYMBOL                            | TEST CONDITIONS  | VALUES                        | UNITS |
| Junction and storage temperature range                        | T <sub>J</sub> , T <sub>Stg</sub> |  | - 40 to 150                   | °C    |
| Maximum internal thermal resistance, junction to case per leg | R <sub>thJC</sub>                 | DC operation   | 0.28                          | °C/W  |
| Typical thermal resistance, case to heatsink per module       | R <sub>thCS</sub>                 | Mounting surface flat, smooth and greased  | 0.1                           |       |
| Mounting torque ± 10 %  | to heatsink                       | A mounting compound is recommended and the torque should be rechecked after a period of 3 hours to allow for the spread of the compound. | 4                             | Nm    |
|   | busbar                            |  | 3                             |       |
| Approximate weight  |                                   |  | 75                            | g     |
|   |                                   |  | 2.7                           | oz.   |
| Case style  |                                   | JEDEC®   | ADD-A-PAK Gen. VII (TO-240AA) |       |

| ΔR CONDUCTION PER JUNCTION |                           |       |       |       |       |                             |       |      |       |      |       |
|----------------------------|---------------------------|-------|-------|-------|-------|-----------------------------|-------|------|-------|------|-------|
| DEVICES                    | SINE HALF WAVE CONDUCTION |       |       |       |       | RECTANGULAR WAVE CONDUCTION |       |      |       |      | UNITS |
|                            | 180°                      | 120°  | 90°   | 60°   | 30°   | 180°                        | 120°  | 90°  | 60°   | 30°  |       |
| VSK.71                     | 0.075                     | 0.088 | 0.113 | 0.155 | 0.228 | 0.06                        | 0.094 | 0.12 | 0.158 | 0.23 | °C/W  |

**Note**

- Table shows the increment of thermal resistance R<sub>thJC</sub> when devices operate at different conduction angles than DC



Fig. 1 - Current Ratings Characteristics



Fig. 4 - Forward Power Loss Characteristics



Fig. 2 - Current Ratings Characteristics



Fig. 5 - Maximum Non-Repetitive Surge Current



Fig. 3 - Forward Power Loss Characteristics



Fig. 6 - Maximum Non-Repetitive Surge Current



Fig. 7 - Forward Power Loss Characteristics



Fig. 8 - Forward Power Loss Characteristics



Fig. 9 - Forward Power Loss Characteristics



Fig. 10 - Forward Voltage Characteristics



Fig. 11 - Thermal Impedance  $Z_{thJC}$  Characteristics

**ORDERING INFORMATION TABLE**

|             |              |          |   |           |          |           |
|-------------|--------------|----------|---|-----------|----------|-----------|
| Device code | <b>VS-VS</b> | <b>K</b> | <b>D</b>  | <b>71</b> | <b>/</b> | <b>16</b> |
|             | ①            | ②        | ③   | ④         |          | ⑤         |
|             | <b>1</b>     | -        | Vishay Semiconductors product                           |           |          |           |
|             | <b>2</b>     | -        | Module type   |           |          |           |
|             | <b>3</b>     | -        | Circuit configuration (see Circuit Configuration table) |           |          |           |
|             | <b>4</b>     | -        | Current code (80 A)                                     |           |          |           |
|             | <b>5</b>     | -        | Voltage code (see Voltage Ratings table)                |           |          |           |

**Note**

- To order the optional hardware go to [www.vishay.com/doc?95172](http://www.vishay.com/doc?95172)



| CIRCUIT CONFIGURATION      |                            |                       |
|----------------------------|----------------------------|-----------------------|
| CIRCUIT DESCRIPTION        | CIRCUIT CONFIGURATION CODE | CIRCUIT DRAWING       |
| Two diodes doubler circuit | D                          | <p><b>VSKD...</b></p> |
| Two diodes common cathode  | C                          | <p><b>VSKC...</b></p> |
| Two diodes common anode    | J                          | <p><b>VSKJ...</b></p> |
| Single diode               | E                          | <p><b>VSKE...</b></p> |

| LINKS TO RELATED DOCUMENTS |  |
|----------------------------|--|
| Dimensions                 | <a href="http://www.vishay.com/doc?95369">www.vishay.com/doc?95369</a> |

## ADD-A-PAK Generation VII - Diode

**DIMENSIONS** in millimeters (inches)







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